

# HMC511LP5/511LP5E

v06.0114



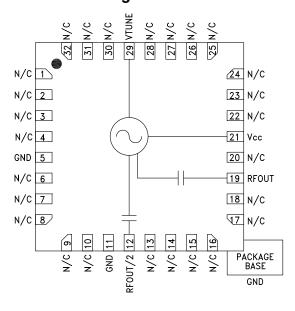
## MMIC VCO WITH HALF FREQUENCY OUTPUT 9.05 - 10.15 GHz

#### Typical Applications

Low noise MMIC VCO w/Half Frequency, for:

- VSAT Radio
- Point to Point/Multi-Point Radio
- Test Equipment & Industrial Controls
- Military End-Use

#### **Functional Diagram**



#### **Features**

Dual Output: Fo = 9.05 - 10.15 GHz

Fo/2 = 4.525 - 5.075 GHz

Pout: +13 dBm

Phase Noise: -115 dBc/Hz @100 kHz Typ.

No External Resonator Needed

32 Lead 5x5mm SMT Package: 25mm²

#### **General Description**

The HMC511LP5 & HMC511LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC511LP5 & HMC511LP5E integrate resonators, negative resistance devices, varactor diodes and feature a half frequency output. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +13 dBm typical from a +5V supply. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

## Electrical Specifications, $T_A = +25^{\circ}$ C, Vcc = +5V

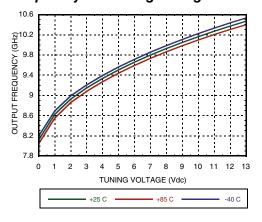
Parameter		Min.	Тур.	Max.	Units
Frequency Range	Fo Fo/2		9.05 - 10.15 4.525 - 5.075		GHz GHz
Power Output	RFOUT/2	+9 +5		+16 +11	dBm dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RFOUT			-115		dBc/Hz
Tune Voltage	Vtune	2		13	V
Supply Current (Icc) (Vcc = +5.0V)		200	265	300	mA
Tune Port Leakage Current (Vtune= 13V)				10	μA
Output Return Loss			2		dB
Harmonics/Subharmonics	1/2 2nd 3rd		38 15 30		dBc dBc dBc
Pulling (into a 2.0:1 VSWR)			8		MHz pp
Pushing @ Vtune= 5V			15		MHz/V
Frequency Drift Rate			0.9		MHz/°C



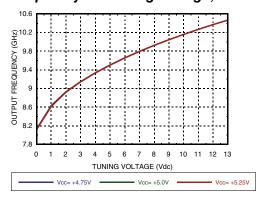


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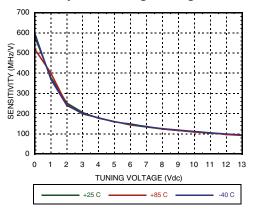
#### Frequency vs. Tuning Voltage



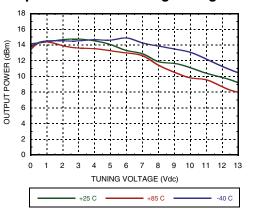
#### Frequency vs. Tuning Voltage, T = 25C



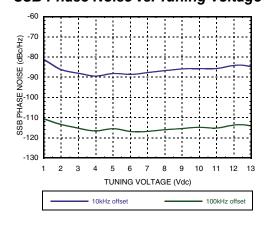
#### Sensitivity vs. Tuning Voltage



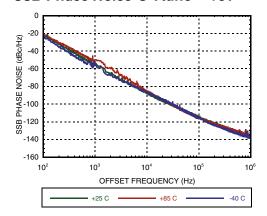
#### **Output Power vs. Tuning Voltage**



#### SSB Phase Noise vs. Tuning Voltage



#### SSB Phase Noise @ Vtune = +5V

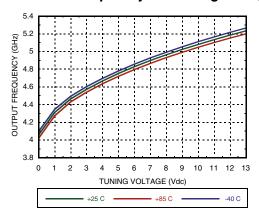




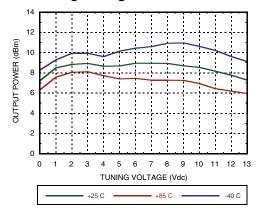


## MMIC VCO WITH HALF FREQUENCY OUTPUT 9.05 - 10.15 GHz

#### RFOUT/2 Frequency vs. Tuning Voltage



# RFOUT/2 Output Power vs. Tuning Voltage



#### **Absolute Maximum Ratings**

Vcc	+5.5 Vdc	
Vtune	0 to +15V	
Storage Temperature	-65 to +150 °C	
ESD Sensitivity (HBM)	Class 1A	

#### Reliability Information

Junction Temperature To Maintain 1 Million Hour MTTF	135 °C
Nominal Junction Temperature (T = +85 °C	126.9 °C
Thermal Resistance (junction to ground paddle)	31.6 °C/W
Operating Temperature	-40 to +85 °C



#### Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
4.75	245
5.0	265
5.25	285

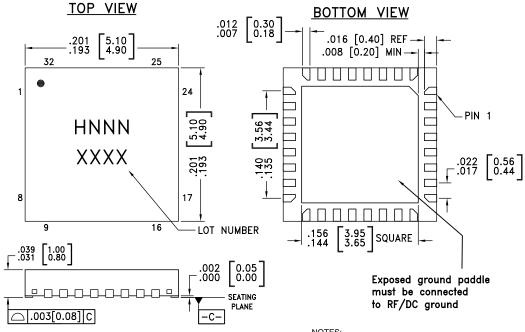
Note: VCO will operate over full voltage range shown above.





## MMIC VCO WITH HALF FREQUENCY OUTPUT 9.05 - 10.15 GHz

#### **Outline Drawing**



#### NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
   PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

#### Package Information

Part Number	Package Body Material Lead		MSL Rating	Package Marking [3]
HMC511LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL3 [1]	H511 XXXX
HMC511LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 [2]	H511 XXXX

- [1] Max peak reflow temperature of 235  $^{\circ}\text{C}$
- [2] Max peak reflow temperature of 260  $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX





## MMIC VCO WITH HALF FREQUENCY OUTPUT 9.05 - 10.15 GHz

### **Pin Descriptions**

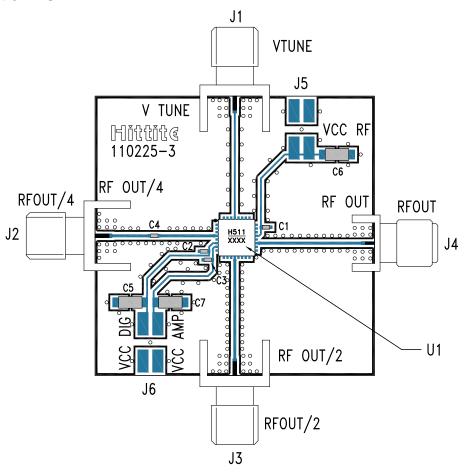
Pin Number	Function	Description	Interface Schematic
1 - 4, 6 - 10, 13 - 18, 20, 22 - 28, 30 - 32	N/C	No Connection. These pins may be connected to RF/ DC ground. Performance will not be affected.	
12	RFOUT/2	Half frequency output (AC coupled).	→ PRFOUT/2
19	RFOUT	RF output (AC coupled).	RFOUT
21	Vcc	Supply Voltage, +5V	VccO 14pF
29	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	VTUNE 0 3nH 4pF
5, 11 Paddle	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	GND =





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#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 110227 [1]

Item	Description	
J1 - J4	PCB Mount SMA RF Connector	
J5	2 mm DC Header	
C1 - C3	100 pF Capacitor, 0402 Pkg.	
C4	1,000 pF Capacitor, 0402 Pkg.	
C5 - C7	2.2 µF Tantalum Capacitor	
U1	HMC511LP5(E) VCO	
PCB [2]	110225 Eval Board	

<sup>[1]</sup> Reference this number when ordering complete evaluation PCB

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and backside ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

<sup>[2]</sup> Circuit Board Material: Arlon 25FR

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## Analog Devices Inc.:

HMC511LP5E 110227-HMC511LP5 HMC511LP5ETR HMC511LP5